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Front Matter: Volume 7406

, "Front Matter: Volume 7406," Proc. SPIE 7406, Nanoepitaxy: Homo- and Heterogeneous Synthesis, Characterization, and Device Integration of Nanomaterials, 740601 (11 September 2009); doi: 10.1117/12.844944

SPIE.

Event: SPIE NanoScience + Engineering, 2009, San Diego, California, United States

PROCEEDINGS OF SPIE

Nanoepitaxy: Homo- and Heterogeneous Synthesis, Characterization, and Device Integration of Nanomaterials

**M. Saif Islam
A. Alec Talin
Stephen D. Hersee**
Editors

**3–4 August 2009
San Diego, California, United States**

Sponsored and Published by
SPIE

Volume 7406

Proceedings of SPIE, 0277-786X, v. 7406

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Author(s), "Title of Paper," in *Nanoepitaxy: Homo- and Heterogeneous Synthesis, Characterization, and Device Integration of Nanomaterials*, edited by M. Saif Islam, A. Alec Talin, Stephen D. Hersee, Proceedings of SPIE Vol. 7406 (SPIE, Bellingham, WA, 2009) Article CID Number.

ISSN 0277-786X

ISBN 9780819476968

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA

Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445

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